TIP131, TIP132 (NPN), TIP137 (PNP)

Darlington Complementary Silicon Power Transistors

Designed for general-purpose amplifier and low-speed switching applications.

Features

- High DC Current Gain $h_{FE} = 2500 (Typ) @ I_C$
 - = 4.0 Adc
- Collector-Emitter Sustaining Voltage @ 30 mAdc
 V_{CEO(sus)} = 80 Vdc (Min) TIP131
 = 100 Vdc (Min) TIP132, TIP137
- Low Collector–Emitter Saturation Voltage
 - $V_{CE(sat)} = 2.0 \text{ Vdc} (Max) @ I_C = 4.0 \text{ Adc}$

 $= 3.0 \text{ Vdc} (\text{Max}) @ I_{\text{C}} = 6.0 \text{ Adc}$

- Monolithic Construction with Built-In Base-Emitter Shunt Resistors
- Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	TIP131	TIP132 TIP137	Unit
Collector-Emitter Voltage	V _{CEO}	80	100	Vdc
Collector-Base Voltage	V _{CB}	80	100	Vdc
Emitter-Base Voltage	V _{EB}	5.0		Vdc
Collector Current – Continuous Peak	Ι _C	8.0 12		Adc
Base Current	I _B	300		mAdc
Total Power Dissipation @ $T_C = 25^{\circ}C$	PD	70		W
Total Power Dissipation @ $T_A = 25^{\circ}C$	PD	2.0		W
Operating and Storage Junction, Temperature Range	T _J , T _{stg}	−65 to +150		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.78	°C/W
Thermal Resistance, Junction-to-Ambient	R _{θJA}	63.5	°C/W

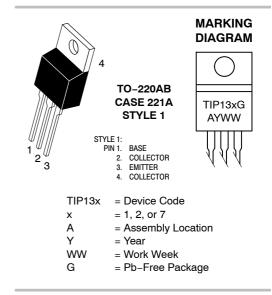
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

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DARLINGTON 8 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 80–100 VOLTS, 70 WATTS



ORDERING INFORMATION

Device	Package	Shipping	
TIP131	TO-220	50 Units/Rail	
TIP131G	TO-220 (Pb-Free)	50 Units/Rail	
TIP132	TO-220	50 Units/Rail	
TIP132G	TO–220 (Pb–Free)	50 Units/Rail	
TIP137	TO-220	50 Units/Rail	
TIP137G	TO-220 (Pb-Free)	50 Units/Rail	

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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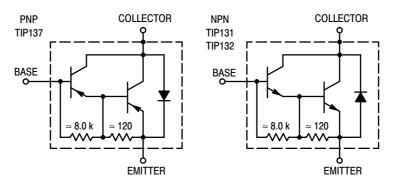


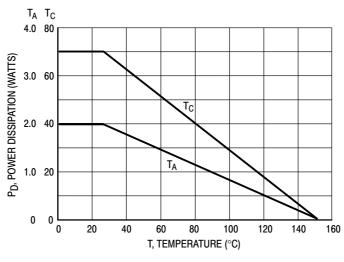
Figure 1. Darlington Circuit Schematic

ELECTRICAL CHARACTERISTICS (T_C = 25° C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS				-	
Collector-Emitter Sustaining Voltage (Note 1) $(I_{C} = 30 \text{ mAdc}, I_{B} = 0)$	TIP131 TIP132, TIP137	V _{CEO(sus)}	80 100		Vdc
Collector Cutoff Current ($V_{CE} = 40 \text{ Vdc}, I_B = 0$) ($V_{CE} = 50 \text{ Vdc}, I_B = 0$)	TIP131 TIP132, TIP137	I _{CEO}		0.5 0.5	mAdc
Collector Cutoff Current ($V_{CB} = 80 \text{ Vdc}, I_E = 0$) ($V_{CB} = 100 \text{ Vdc}, I_E = 0$)	TIP131 TIP132, TIP137	I _{CBO}		0.2 0.2	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}, I_C = 0$)		I _{EBO}	-	5.0	mAdc
ON CHARACTERISTICS (Note 1)				-	
DC Current Gain ($I_C = 1.0 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$) ($I_C = 4.0 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc}$)		h _{FE}	500 1000	_ 15000	-
Collector-Emitter Saturation Voltage ($I_C = 4.0 \text{ Adc}, I_B = 16 \text{ mAdc}$) ($I_C = 6.0 \text{ Adc}, I_B = 30 \text{ mAdc}$)		V _{CE(sat)}		2.0 3.0	Vdc
Base-Emitter On Voltage $(I_C = 4.0 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc})$		V _{BE(on)}	-	2.5	Vdc

1. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

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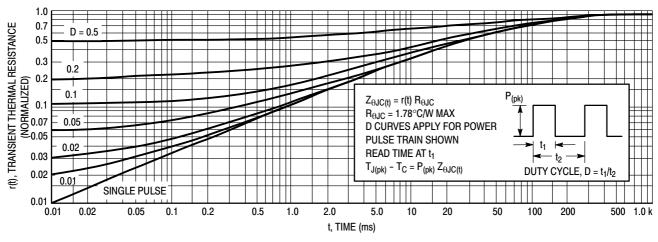


Figure 3. Thermal Response

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